

isc Silicon NPN Power Transistor

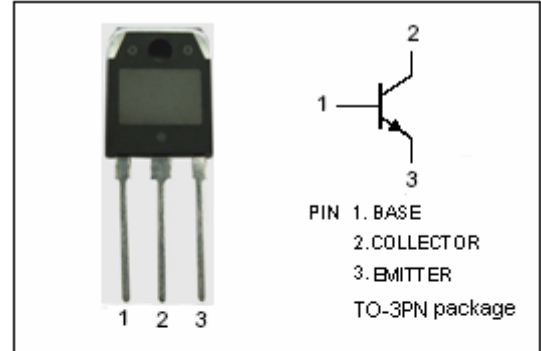
2SC4237

DESCRIPTION

- Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(SUS)} = 800V(\text{Min})$
- Fast Switching speed

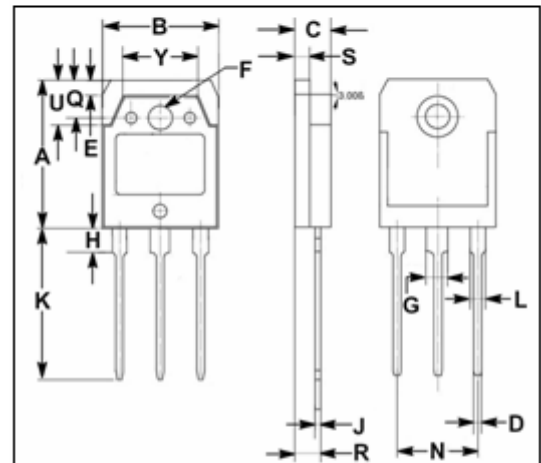
APPLICATIONS

- Color TV horizontal output applications



ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	1200	V
$V_{CEO}$	Collector-Emitter Voltage	800	V
$V_{EBO}$	Emitter-Base Voltage	7	V
$I_C$	Collector Current-Continuous	10	A
$I_{CM}$	Collector Current-Peak	20	A
$I_B$	Base Current-Continuous	4	A
$I_{BM}$	Base Current-Peak	8	A
$P_T$	Total Power Dissipation @ $T_C=25^\circ\text{C}$	150	W
$T_J$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature Range	-55~150	°C



DIM	mm	
	MIN	MAX
A	19.90	20.10
B	15.38	15.42
C	4.75	4.85
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.98	3.02
H	3.20	3.40
J	0.595	0.605
K	19.95	20.25
L	1.98	2.02
N	10.89	10.91
Q	4.95	5.05
R	3.35	3.45
S	1.995	2.005
U	5.90	6.10
Y	9.90	10.10

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	0.83	°C/W

**isc Silicon NPN Power Transistor****2SC4237****ELECTRICAL CHARACTERISTICS** $T_C=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C=0.2\text{A}; I_B=0$	800			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=5\text{A}; I_B=1\text{A}$			1.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=5\text{A}; I_B=1\text{A}$			1.5	V
$I_{CBO}$	Collector Cutoff Current	At rated Voltage			100	$\mu\text{A}$
$I_{CEO}$	Collector Cutoff Current	At rated Voltage			100	$\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current	At rated Voltage			100	$\mu\text{A}$
$h_{FE-1}$	DC Current Gain	$I_C=5\text{A}; V_{CE}=5\text{V}$	8			
$h_{FE-2}$	DC Current Gain	$I_C=1\text{mA}; V_{CE}=5\text{V}$	5			
$f_T$	Current-Gain—Bandwidth Product	$I_C=1\text{A}; V_{CE}=10\text{V}$		8		MHz

## Switching times

$t_{on}$	Turn-on Time	$I_C=5\text{A}, I_{B1}=1\text{A}; I_{B2}=-2\text{A}$ $R_L=50\Omega; V_{BB2}=4\text{V}$			0.5	$\mu\text{s}$
$t_{stg}$	Storage Time				3.5	$\mu\text{s}$
$t_f$	Fall Time				0.3	$\mu\text{s}$